

# PNP SILICON TRANSISTOR 2SA1627

**DESCRIPTION** The 2SA1627 is designed for general purpose amplifier and high

speed switching applications.

**FEATURES** 

- High Voltage.
- High Speed Switching.
- Low Collector Saturation Voltage.

#### **ABSOLUTE MAXIMUM RATINGS**

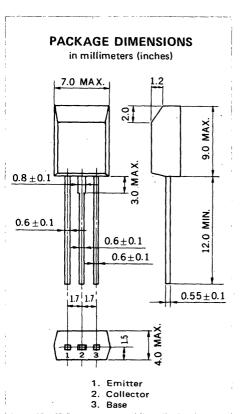
Maximum Temperatures

Storage Temperature . . . . . . . . . . . . . . . . -55 to +150 °C Junction Temperature . . . . . . . . . . . . . . . . 150 °C Maximum Maximum Power Dissipation ( $T_a = 25$  °C) Total Power Dissipation . . . . . . . . . . . . . 1.0

Max

ximum Voltages and Currents ( $T_a = 25$ °C)						
$V_{CBO}$	Collector to Base Voltage600	٧				
$V_{CEO}$	Collector to Emitter Voltage600	٧				
$V_{EBO}$	Emitter to Base Voltage7.0	<b>V</b> .				
Ic	Collector Current (DC)	Α				
1 <sub>C</sub>	Collector Current (pulse)*2.0	Α				

<sup>\*</sup> PW  $\leq$  10 ms, Duty Cycle  $\leq$  50 %



## ELECTRICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
hFE1**	DC Current Gain	30	58	120	_	$V_{CE} = -5.0 \text{ V, } I_{C} = -0.1 \text{ A}$
hFE2**	DC Current Gain	5	19		-	$V_{CE} = -5.0 \text{ V}, I_{C} = -0.5 \text{ A}$
f <sub>T</sub>	Gain Bandwidth Product	. 10	28		MHz	$V_{CE} = -10 \text{ V, I}_{E} = 0.1 \text{ A}$
C <sub>ob</sub>	Output Capacitance		42	50	pF	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$
СВО	Collector Cutoff Current			-10	μΑ	$V_{CB} = -600 \text{ V}, I_E = 0$
<sup>1</sup> EBO	Emitter Cutoff Current			-10	μА	$V_{EB} = -7.0 \text{ V, I}_{C} = 0$
VCE(sat)**	Collector Saturation Voltage		-0.28	-0.5	V	$I_C = -0.3 \text{ A}, I_B = -0.06 \text{ A}$
V <sub>BE(sat)</sub> **	Base Saturation Voltage		-0.85	-1.2	V	$I_C = -0.3 \text{ A}, I_B = -0.06 \text{ A}$
t <sub>on</sub>	Turn On Time		0.1	0.5	μs	$\int I_{C} = -0.5 \text{ A, R}_{L} = 500 \Omega$
t <sub>stg</sub>	Storage Time		3.5	5.0	μs	$I_{B1} = -I_{B2} = -0.1 \text{ A}$
tf	Fall Time		0.08	0.5	μs	$V_{CC} = -250 \text{ V}$

<sup>\*\*</sup> Pulsed PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2 %

### Classification of hee1

Rank	M	L	к
Range	30 to 60	40 to 80	60 to 120

Test Conditions:  $V_{CB} = -5.0 \text{ V}$ ,  $I_{C} = -0.1 \text{ A}$ 

## TYPICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)

